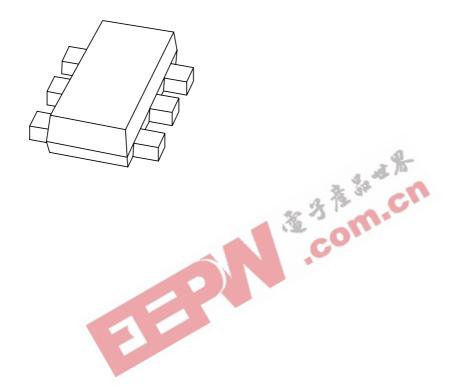
DISCRETE SEMICONDUCTORS

DATA SHEET



BAT74VSchottky barrier double diode

Product specification

2002 Sep 02





Schottky barrier double diode

BAT74V

FEATURES

- · Low forward voltage
- Low capacitance
- Ultra small SMD plastic package
- Flat leads: excellent coplanarity and improved thermal behaviour.

APPLICATIONS

- · Ultra high-speed switching
- · Voltage clamping
- · Line termination
- Inverse polarity protection.

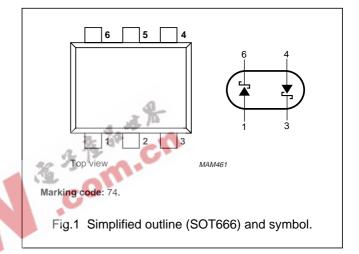
DESCRIPTION

Planar Schottky barrier double diode with an integrated guard ring for stress protection.

Two separate dies encapsulated in a SOT666 ultra small SMD plastic package.

PINNING

PIN	DESCRIPTION		
1	node 1		
2	not connected		
3	cathode 2		
4	anode 2		
5	not connected		
6	cathode 1		



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		_	30	V
I _F	continuous forward current		_	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	300	mA
I _{FSM}	non-repetitive peak forward current	t _p < 10 ms		600	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	_	230	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	125	°C
T _{amb}	operating ambient temperature		-65	+125	°C

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CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	continuous forward voltage	I _F = 0.1 mA	240	mV
		I _F = 1 mA	320	mV
		I _F = 10 mA	400	mV
		I _F = 30 mA	500	mV
		I _F = 100 mA; note 1; see Fig.2	800	mV
I _R	reverse current	V _R = 25 V; note 1; see Fig.3	2	μΑ
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; see Fig.4	10	pF

Note

1. Pulse test: t_p = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	416	K/W

Note

1. Refer to SOT666 standard mounting conditions.

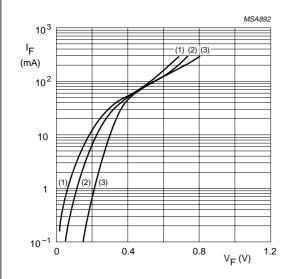
Soldering

The only recommended soldering method is reflow soldering.

Schottky barrier double diode

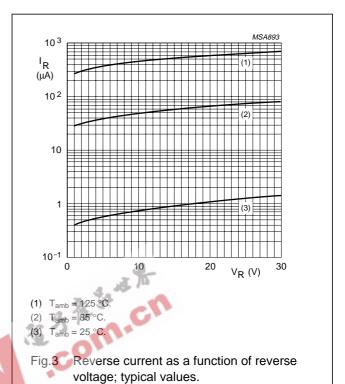
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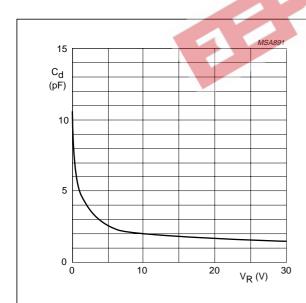
GRAPHICAL DATA



- (1) $T_{amb} = 125 \,^{\circ}C$.
- (2) $T_{amb} = 85 \,^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.





 $f = 1 \text{ MHz}; T_{amb} = 25 \, ^{\circ}\text{C}.$

Fig.4 Diode capacitance as a function of reverse voltage; typical values.

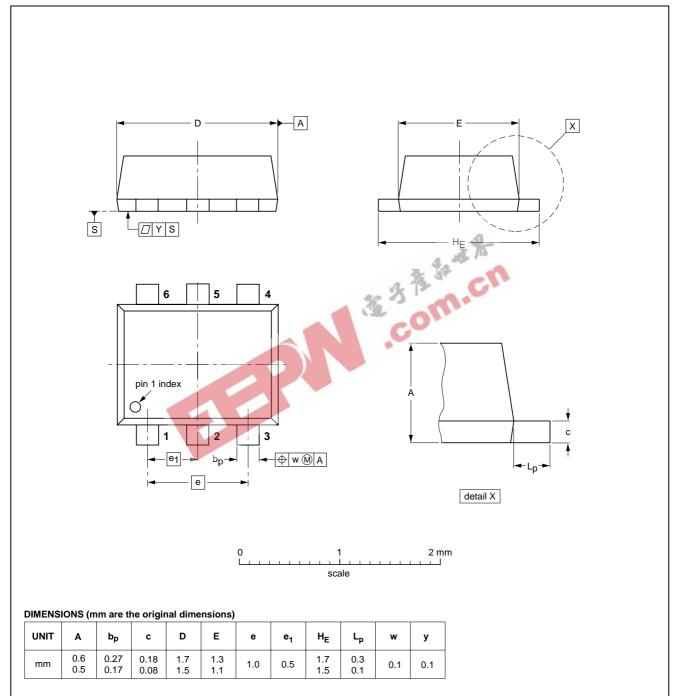
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PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT666						-01-01-04- 01-08-27	
				1			

Schottky barrier double diode

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DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

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NOTES



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